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### SS9012

## 1W Output Amplifier of Potable Radios in Class B Push-pull Operation.

- High total power dissipation. (P<sub>T</sub>=625mW)
- High Collector Current. (I<sub>C</sub>= -500mA)
   Complementary to SS9013
- Excellent  $h_{\text{FE}}$  linearity.



1. Emitter 2. Base 3. Collector

## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V <sub>CBO</sub>	Collector-Base Voltage	-40	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-20	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
I <sub>C</sub>	Collector Current	-500	mA	
P <sub>C</sub>	Collector Power Dissipation	625	mW	
TJ	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C	

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-40			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -1 \text{ mA}, I_B = 0$	-20			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = -100 \mu A, I_C = 0$	-5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = -25V, I_{E} = 0$			-100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -3V, I_{C} = 0$			-100	nA
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = -1V, I_{C} = -50mA$	64	120	202	
$h_{FE2}$		$V_{CE} = -1V, I_{C} = -500 \text{mA}$	40	90		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$		-0.18	-0.6	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$		-0.95	-1.2	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = -1V, I_{C} = -10mA$	-0.6	-0.67	-0.7	V

### **h**<sub>FE</sub> Classification

Classification	D	E	F	G	Н
h <sub>FE1</sub>	64 ~ 91	78 ~ 112	96 ~ 135	112 ~ 166	144 ~ 202

# **Typical Characteristics**

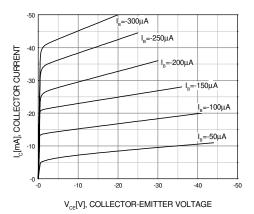


Figure 1. Static Characteristic

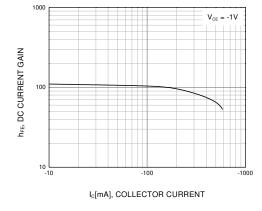


Figure 2. DC current Gain

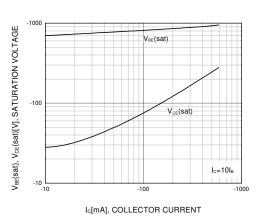


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

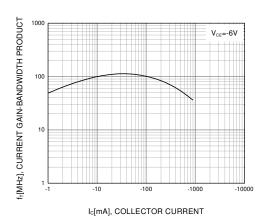
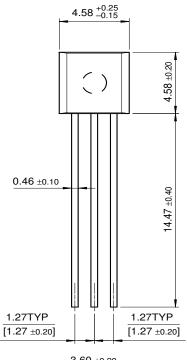
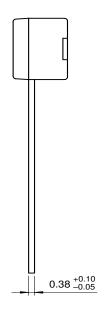


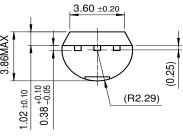
Figure 4. Current Gain Bandwidth Product

# **Package Dimensions**

TO-92







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EnSigna™	I <sup>2</sup> C <sup>TM</sup>	OCXTM	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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